

## **DMP3030SN** P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

**Features** 

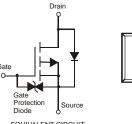
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead Free By Design/RoHS Compliant (Note 2)
- **ESD Protected Gate**
- "Green" Device (Note 4)
- Qualified to AEC-Q101 standards for High Reliability

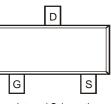
#### **Mechanical Data**

- Case: SC59
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.014 grams (approximate)

SC59







EQUIVALENT CIRCUIT

#### Internal Schematic

## Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

0			
Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-30	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Drain Current (Note 1) Steady State	Ι <sub>D</sub>	-0.7	A
Pulsed Drain Current (Note 3)	I <sub>DM</sub>	-2.8	A

#### Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	Pd	500	mW
Thermal Resistance, Junction to Ambient	$R_{ ext{ heta}JA}$	250	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +150	°C

#### Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30			V	$V_{GS} = 0V, I_{D} = -250\mu A$		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-10	μΑ	$V_{DS} = -30V, V_{GS} = 0V$		
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 5)								
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	—	-3.0	V	$V_{DS} = -10V, I_D = -1.0mA$		
Static Drain-Source On-Resistance	Rds (ON)	_	0.20 0.35	0.25 0.45	Ω	V <sub>GS</sub> = -10V, I <sub>D</sub> = -0.4A V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -0.4A		
Forward Transfer Admittance	Y <sub>fs</sub>	_	1	_	S	$V_{DS} = -10V, I_{D} = -0.4A$		
Diode Forward Voltage (Note 5)	V <sub>SD</sub>	_	-0.8	-1.1	V	$V_{GS} = 0V, I_{S} = -0.7A$		
DYNAMIC CHARACTERISTICS	· · ·			•		•		
Input Capacitance	C <sub>iss</sub>	_	160		pF			
Output Capacitance	C <sub>oss</sub>	_	120		pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	50	_	pF			
SWITCHING CHARACTERISTICS			_		_			
Turn-On Delay Time	t <sub>D(ON)</sub>	—	10	—	ns			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	25	_	ns	V <sub>DD</sub> = -10V, I <sub>D</sub> = -0.4A,		
Turn-On Rise Time	t <sub>r</sub>		25		ns	$V_{GS}$ = -5.0V, $R_{GEN}$ = 50 $\Omega$		
Turn-Off Fall Time	t <sub>f</sub>	_	40	_	ns	1		

1. Device mounted on FR-4 PCB.

No purposefully added lead. 2.

3. Pulse width  $\leq 10\mu$ S, Duty Cycle  $\leq 1\%$ .

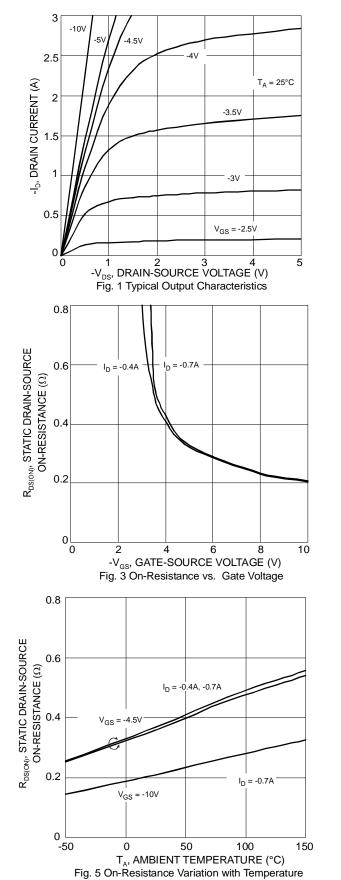
Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php. 4.

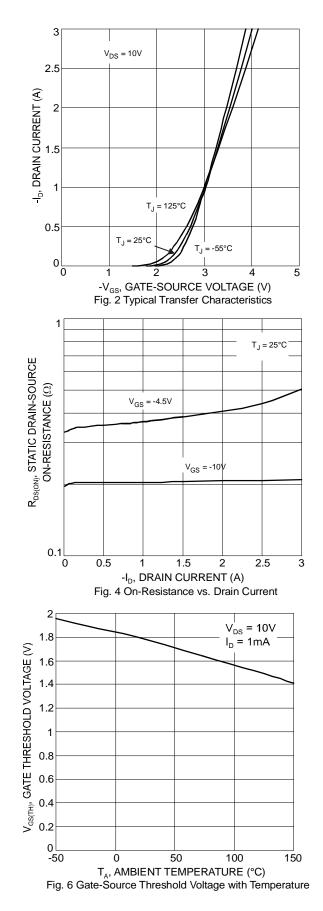
5. Short duration pulse test used to minimize self-heating effect.

Notes:





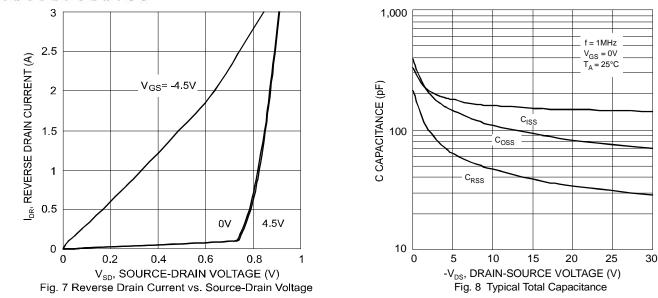




DMP3030SN Document number: DS30787 Rev. 5 - 2



## **DMP3030SN**

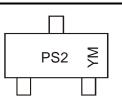


### Ordering Information (Note 6)

Part Number	Case	Packaging
DMP3030SN-7	SC59	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

#### **Marking Information**

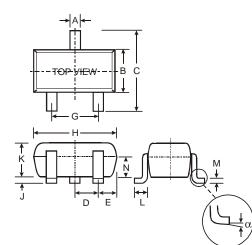


PS2 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

## Date Code Key

Year	200	6	2007		2008	20	09	2010		2011	1	2012
Code	Т		U		V	V	N	Х		Y		Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

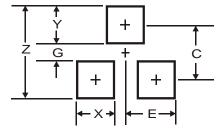
#### **Package Outline Dimensions**



	SC59				
Dim	Min	Max			
Α	0.35	0.50			
В	1.50	1.70			
С	2.70	3.00			
D	0.9	95			
E		_			
G	1.90				
н	2.90	3.10			
J	0.013	0.10			
K	1.00	1.30			
L	0.35	0.55			
М	0.10	0.20			
N	0.70	0.80			
α	0°	8°			
All Dimensions in mm					



#### Suggested Pad Layout



Dimensions	Value (in mm)
Z	4.0
G	1.2
Х	0.9
Y	1.4
С	2.6
E	0.95

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